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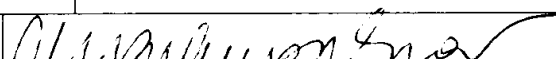
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Sheet		1	of	1	
				Application Number	
				Filing Date	December 18, 2001
				First Named Inventor	Akihiko ISHIBASHI et al.
				Group Art Unit	
				Examiner Name	
				Attorney Docket Number	740819-720

U.S. PATENT DOCUMENTS						
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MH		S. NAKAMURA et al., "High-Power, Long-Lifetime InGaN/GaN/AlGaIn-Based Laser Diodes Grown on Pure GaN Substrates": Japanese Journal of Applied Physics, Vol. 37, (1998, pp. L309-L312, Part 2, No. 3B, March 15, 1998.	

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